

# BIPOLAR ANALOG INTEGRATED CIRCUIT

# $\mu$ PC1032H

## DUAL LOW NOISE PREAMPLIFIER

## SILICON BIPOLAR MONOLITHIC INTEGRATED CIRCUIT

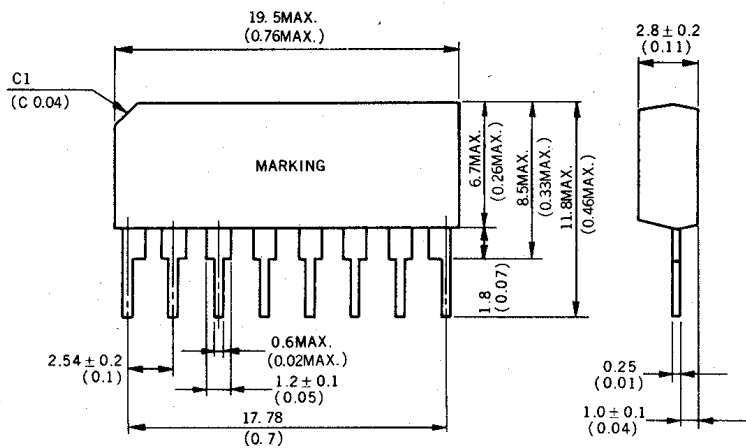
### DESCRIPTION

The  $\mu$ PC1032H is a silicon monolithic integrated circuit designed for use as a 2 channel preamplifier for a car stereo set. The device has features of low noise, high gain, high output voltage and wide supply voltage range.

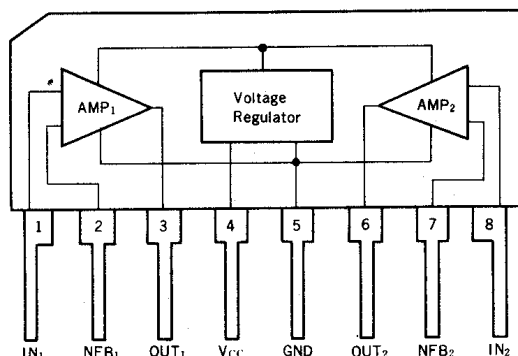
Especially, as an advanced production process is used, the device has an excellent feature of very low pulsive noise. An internal voltage regulator circuit permits the  $\mu$ PC1032H to operate satisfactorily over wide variation of supply voltage.

### PACKAGE DIMENSIONS

in millimeters (inches)



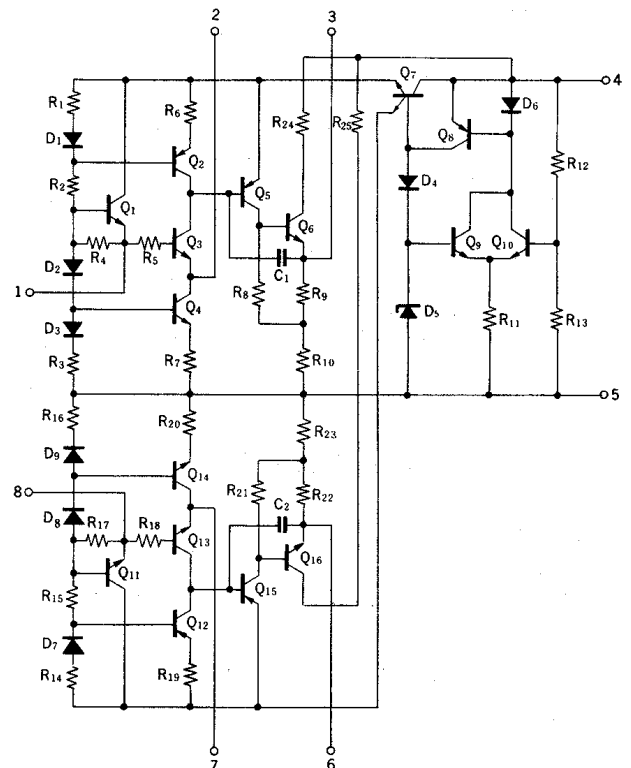
### CONNECTION DIAGRAM



### FEATURES

- Two channel
- Wide supply voltage range
- Minimum number of external parts required
- Low noise, especially low pulsive noise
- SIP assures easy mounting on printed circuit board.

### EQUIVALENT CIRCUIT



## ABSOLUTE MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

|                       |           |             |                  |
|-----------------------|-----------|-------------|------------------|
| Supply Voltage        | $V_{CC}$  | 18          | V                |
| Package Dissipation   | $P_D$     | 270*        | mW               |
| Operating Temperature | $T_{opt}$ | -20 to +75  | $^\circ\text{C}$ |
| Storage Temperature   | $T_{stg}$ | -40 to +125 | $^\circ\text{C}$ |

\* $T_a = 75^\circ\text{C}$

## RECOMMENDED CONDITIONS ( $T_a = 25^\circ\text{C}$ )

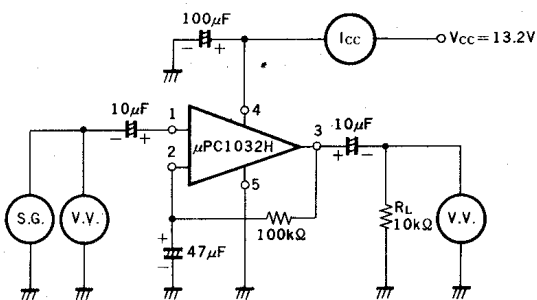
|                               |          |                    |                  |
|-------------------------------|----------|--------------------|------------------|
| Operating Supply Voltage      | $V_{CC}$ | 13.2               | V                |
| Supply Voltage Range          | $V_{CC}$ | 8 to 17            | V                |
| Operating Ambient Temperature |          | -20 to +75         | $^\circ\text{C}$ |
| Load impedance                |          | 10 k $\Omega$ TYP. |                  |

## ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ , $V_{CC} = 13.2\text{V}$ , $f = 1\text{ kHz}$ , $R_L = 10\text{ k}\Omega$ )

| CHARACTERISTIC                 | SYMBOL    | MIN. | TYP. | MAX. | UNIT                 | TEST CIRCUIT | TEST CONDITIONS  |
|--------------------------------|-----------|------|------|------|----------------------|--------------|--|
| Circuit Current                | $I_{CC}$  |      | 7    | 11.0 | mA                   | ①            | $v_{in} = 0$   |
| Open Loop Voltage Gain         | $A_{vO}$  | 70   | 81   |      | dB                   | ①            | $v_o = 0.3\text{V}$  |
| Voltage Gain                   | $A_v$     | 33.5 | 35   | 35.5 | dB                   | ②            | $v_o = 0.3\text{V}$ , $R_{NF} = 1.8\text{ k}\Omega$                                |
| Maximum Output Voltage         | $V_{OM}$  | 1.1  | 1.7  |      | V                    | ③            | T.H.D. = 1%, $NAB \approx 35\text{ dB}$  |
| Total Harmonic Distortion      | T.H.D.    |      | 0.1  | 0.3  | %                    | ③            | $v_o = 0.3\text{V}$ , $NAB \approx 35\text{ dB}$                                   |
| Input Impedance                | $r_i$     | 50   | 100  |      | k $\Omega$           | ③            |  |
| Equivalent Input Noise Voltage | $v_{nin}$ |      | 1.4  | 2.0  | $\mu\text{V r.m.s.}$ | ④            | $R_G = 2.2\text{ k}\Omega$ , $NAB \approx 35\text{ dB}$                            |
| Cross Talk                     |           |      | -62  |      | dB                   | ⑤            | $v_o = 1\text{V}$ , (The other channel $v_{in} = 0$ , $R_G = 2.2\text{ k}\Omega$ ) |
| Channel Balance                |           | -0.3 | 0    | +0.3 | dB                   | ⑤            | $v_o = 0.3\text{V}$  |

## TEST CIRCUITS

①  $I_{CC}$ ,  $A_{vO}$  Test Circuit



②  $A_v$  Test Circuit (for Ch. 1)

